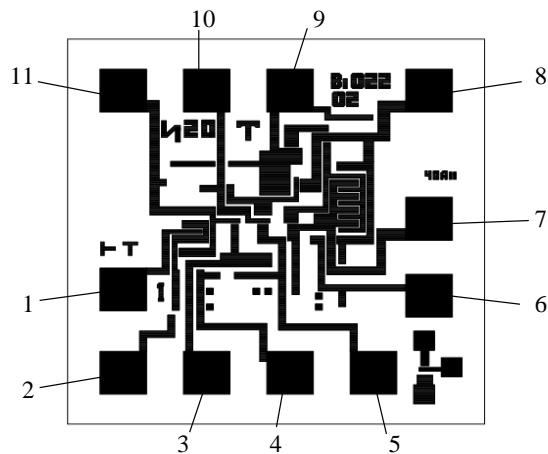
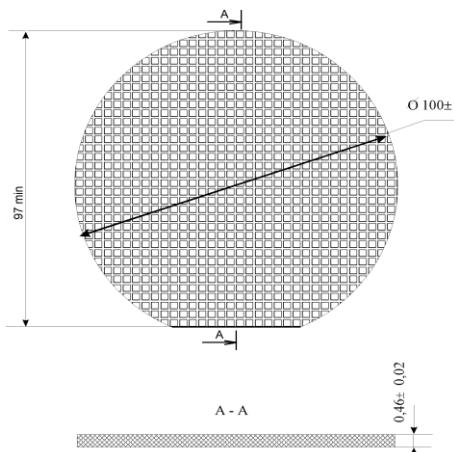


**Low Frequency Amplifier αRD960AH4**


Pin	Designation
1	Input
2	Technological
3	General
4	Technological
5	Technological
6	Feedback
7	General
8	Output
9	Positive Supply
10	Correction
11	Correction

Size of chip: (1,2x1,2)mm

## Electrical Characteristics

TA = +25°C

Parameter	Conditions	Min Value	Max value	Units
Noise voltage	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ	-	1,5	mV
Supply Current	U <sub>CC</sub> =6,9V	-	15	mA
Lower cutoff frequency At 1.4 dB	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, U <sub>I</sub> =1,5 mV	-	0,02	kHz
Upper cutoff frequency At 1.4 dB	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, U <sub>I</sub> =1,5 mV	100	-	kHz
Large Signal Voltage Gain	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, f=1 kHz, U <sub>O</sub> =0,8 V	100	350	
Harmonic coefficient	U <sub>CC</sub> =5,7V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, f=1 kHz, U <sub>O</sub> =0,8 V	-	2	%
Relative instability of the voltage gain	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, f=1 kHz, U <sub>O</sub> =0,8 V	-	±10	%
Input resistance	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, U <sub>I</sub> =1,5 mV f=1 kHz,	10		kΩ
Output resistance	U <sub>CC</sub> =6,3V, R <sub>L</sub> = 0,5 kΩ, R <sub>G</sub> = 0,6 kΩ, f=1 kHz, U <sub>O</sub> =0,8 V	-	0,1	kΩ

Microcircuits are made under supervision of Quality Department, checked and there correspond specification